



**DMG1013UWQ** 

#### P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

#### **Mechanical Data**

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 •
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.006 grams (Approximate)



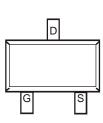


Top View



Equivalent Circuit

Drain



Top View

#### Ordering Information (Note 5)

Part Number	Case	Packaging
DMG1013UWQ-7	SOT323	3000 / Tape & Reel
DMG1013UWQ-13	SOT323	10000 / Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

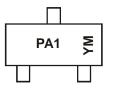
Notes:

and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product\_compliance\_definitions.html.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



PA1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: D = 2016)M = Month (ex: 9 = September)

Date Code Key

Year	2008		2015	2016	2017	2018	2019	2020	2021	2022	2023	2024
Code	V		С	D	Е	F	G	Н		J	К	L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
month	Vull	100	intai	1.0		• • • • • • • • • • • • • • • • • • • •						



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Chara	Symbol	Value	Unit	
Drain-Source Voltage	V <sub>DSS</sub>	-20	V	
Gate-Source Voltage	V <sub>GSS</sub>	±6	V	
Continuous Drain Current (Note 6)	Steady State	ID	-0.82 -0.54	A
Pulsed Drain Current (Note 7)	I <sub>DM</sub>	-3	A	

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	PD	0.31	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 6)	R <sub>0JA</sub>	398	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

 Device mounted on FR-4 PCB, with minimum recommended pad layout.
Repetitive rating, pulse width limited by junction temperature. Notes:

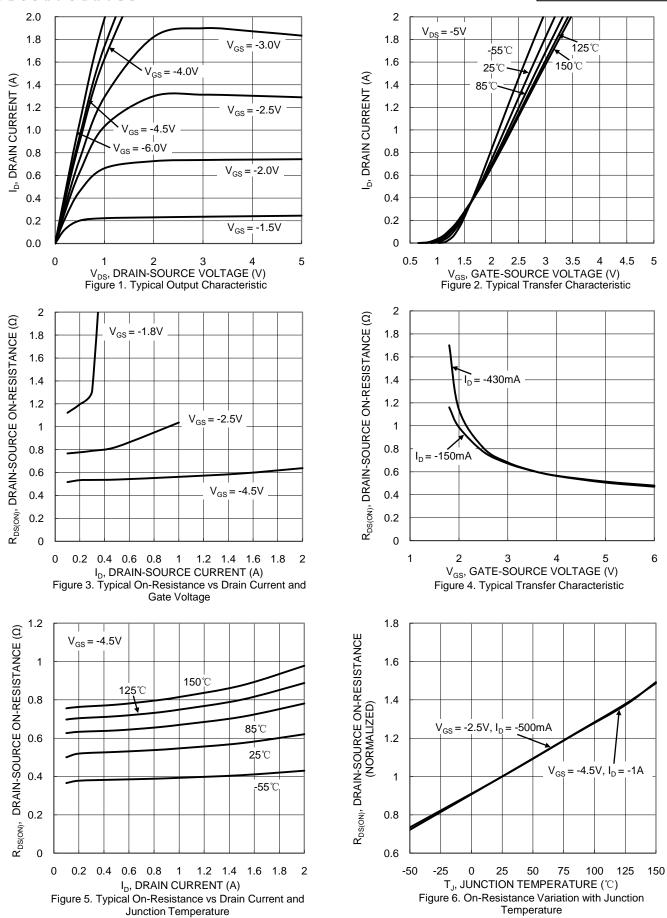
# Electrical Characteristics (@T<sub>A</sub> = +25°C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)						•	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	-	-	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	I <sub>DSS</sub>	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage		-	-	±2.0	μA	$V_{GS} = \pm 4.5 V$ , $V_{DS} = 0 V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.5	-	-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$	
		-	0.5	0.75 1.05		$V_{GS} = -4.5V, I_D = -430mA$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		0.7		Ω	$V_{GS} = -2.5V, I_D = -300mA$	
			1.0	1.5		$V_{GS} = -1.8V, I_D = -150mA$	
Forward Transfer Admittance	Y <sub>fs</sub>	-	0.9	-	s	$V_{DS} = -10V, I_D = -250mA$	
Diode Forward Voltage	V <sub>SD</sub>		-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -150mA$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	Ciss	-	59.76	-	pF		
Output Capacitance	Coss	-	12.07	-	pF	$V_{DS} = -16V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	-	6.36	-	pF	1 = 1.00012	
Total Gate Charge	Qg	-	622.4	-	рС		
Gate-Source Charge	Q <sub>gs</sub>	-	100.3	-	рС	$V_{GS} = -4.5V, V_{DS} = -10V,$	
Gate-Drain Charge	Q <sub>gd</sub>	-	132.2	-	рС	– I <sub>D</sub> = -250mA	
Turn-On Delay Time	t <sub>D(ON)</sub>	-	5.1	-	ns		
Turn-On Rise Time	t <sub>R</sub>	-	8.1	-	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>	-	28.4	-	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$	
Turn-Off Fall Time	t <sub>F</sub>	-	20.7	-	ns	$-I_{\rm D} = -200 {\rm mA}$	

8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to production testing. Notes:



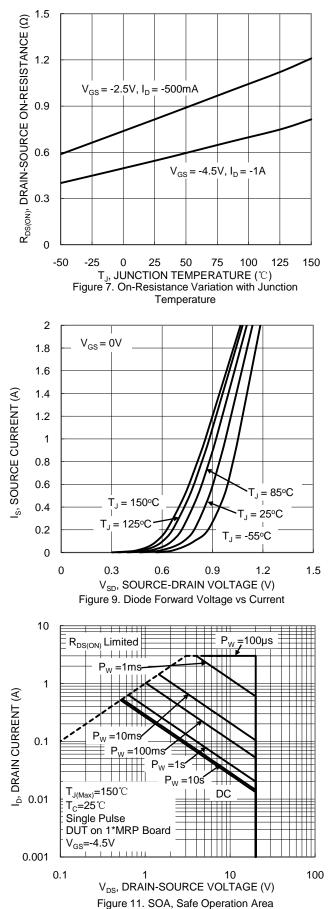
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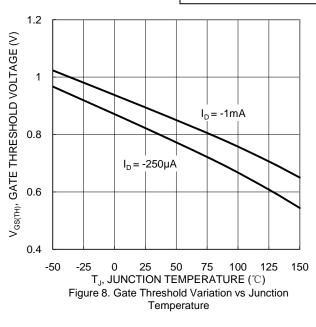


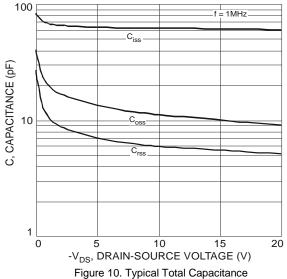
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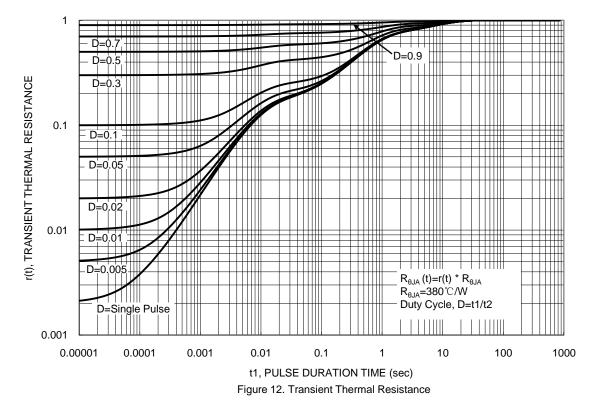
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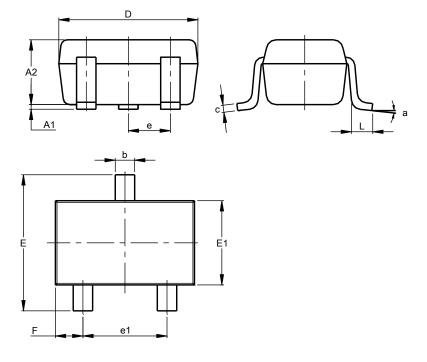




# **Package Outline Dimensions**

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

SOT323

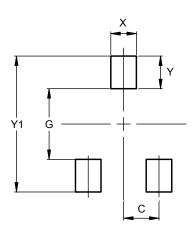


	SOT323						
Dim	Min	Max	Тур				
A1	0.00	0.10	0.05				
A2	0.90	1.00	0.95				
b	0.25	0.40	0.30				
С	0.10	0.18	0.11				
D	1.80	2.20	2.15				
Е	2.00	2.20	2.10				
E1	1.15	1.35	1.30				
е	0.650 BSC						
e1	1.20	1.40	1.30				
F	0.375	0.475	0.425				
L	0.25	0.40	0.30				
а		8°					
All	Dimen	sions	in mm				

### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/\_files/datasheets/ap02001.pdf for the latest version.

#### SOT323



Dimensions	Value		
	(in mm)		
С	0.650		
G	1.300		
Х	0.470		
Y	0.600		
Y1	2.500		



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